

Triple 3-Input AND Gate

High-Performance Silicon-Gate CMOS

MC74AC11, MC74ACT11

Features

- Outputs Source/Sink 24 mA
- 'ACT11 Has TTL Compatible Inputs
- These are Pb-Free Devices

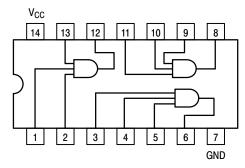
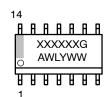


Figure 1. Pinout: 14-Lead Packages Conductors (Top View)

MARKING DIAGRAM



G or ■



XXXXXX = Specific Device Code
A = Assembly Location
WL or L = Wafer Lot
Y = Year
WW or W = Work Week

ORDERING INFORMATION

= Pb-Free Package

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

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MAXIMUM RATINGS

| Symbol | Parameter | Value | Unit |
|-----------------------|-------------------------------------------------------------------------------|-----------------------------------|------|
| V _{CC} | DC Supply Voltage | -0.5 to +6.5 | V |
| VI | DC Input Voltage | $-0.5 \le V_{I} \le V_{CC} + 0.5$ | V |
| Vo | DC Output Voltage (Note 1) | $-0.5 \le V_{O} \le V_{CC} + 0.5$ | V |
| I _{IK} | DC Input Diode Current | ±20 | mA |
| I _{OK} | DC Output Diode Current | ±50 | mA |
| I _O | DC Output Sink/Source Current | ±50 | mA |
| I _{CC} | DC Supply Current per Output Pin | ±50 | mA |
| I _{GND} | DC Ground Current per Output Pin | ±50 | mA |
| T _{STG} | Storage Temperature Range | -65 to +150 | °C |
| TL | Lead temperature, 1 mm from Case for 10 Seconds | 260 | °C |
| TJ | Junction temperature under Bias | + 150 | °C |
| $\theta_{\sf JA}$ | Thermal Resistance (Note 2) | 116 | °C/W |
| P_{D} | Power Dissipation in Still Air at 25°C | 1077 | mW |
| MSL | Moisture Sensitivity | Level 1 | |
| F _R | Flammability Rating Oxygen Index: 30% – 35% | UL 94 V-0 @ 0.125 in | |
| V _{ESD} | ESD Withstand Voltage Human Body Model (Note 3) Charged Device Model (Note 4) | > 2000 > 1000 | V |
| I _{Latch-Up} | Latch-Up Performance Above V _{CC} and Below GND at 85°C (Note 5) | ±100 | mA |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

- 1. I_O absolute maximum rating must be observed.
- 2. The package thermal impedance is calculated in accordance with JESD51-7.
- 3. Tested to EIA/JESD22-A114-A.
- 4. Tested to JESD22-C101-A.
- 5. Tested to EIA/JESD78.

RECOMMENDED OPERATING CONDITIONS

| Symbol | Parameter | | Min | Тур | Max | Unit |
|------------------------------------|---------------------------------------------------------------------|-------------------------|-----|-----|-----------------|-------|
| | O and Mallana | 'AC | 2.0 | 5.0 | 6.0 | .,, |
| V _{CC} | Supply Voltage | 'ACT | 4.5 | 5.0 | 5.5 | V |
| V _{in} , V _{out} | DC Input Voltage, Output Voltage (Ref. to GND) | | 0 | - | V _{CC} | V |
| t _r , t _f | Input Rise and Fall Time (Note 1) 'AC Devices except Schmitt Inputs | V _{CC} @ 3.0 V | - | 150 | - | |
| | | V _{CC} @ 4.5 V | - | 40 | - | ns/V |
| | | V _{CC} @ 5.5 V | - | 25 | - | |
| | Input Rise and Fall Time (Note 2) | V _{CC} @ 4.5 V | - | 10 | - | no // |
| t _r , t _f | 'ACT Devices except Schmitt Inputs | V _{CC} @ 5.5 V | - | 8.0 | - | ns/V |
| T _A | Operating Ambient Temperature Range | | -40 | 25 | 85 | °C |
| I _{OH} | Output Current – High | | - | - | -24 | mA |
| I _{OL} | Output Current - Low | | - | - | 24 | mA |

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

1. V_{in} from 30% to 70% V_{CC}; see individual Data Sheets for devices that differ from the typical input rise and fall times.

2. V_{in} from 0.8 V to 2.0 V; see individual Data Sheets for devices that differ from the typical input rise and fall times.

DC CHARACTERISTICS

| | | | 74 | AC | 74AC | | |
|------------------|--------------------------------------|---------------------|-------------------------|----------------------|---------------------------------------|------|-----------------------------------------------------------------------------------------------------|
| Symbol | Parameter | V _{CC} (V) | T _A = +25°C | | T _A = -40°C to +85°C | Unit | Conditions |
| | | | Тур | Guar | anteed Limits | 1 | |
| V _{IH} | Minimum High Level Input Voltage | 3.0 4.5 5.5 | 1.5 2.25 2.75 | 2.1 3.15 3.85 | 2.1 3.15 3.85 | V | V _{OUT} = 0.1 V or V _{CC} – 0.1 V |
| V _{IL} | Maximum Low Level Input Voltage | 3.0 4.5 5.5 | 1.5 2.25 2.75 | 0.9 1.35 1.65 | 0.9 1.35 1.65 | V | V _{OUT} = 0.1 V or V _{CC} – 0.1 V |
| V _{OH} | Minimum High Level Output Voltage | 3.0 4.5 5.5 | 2.99 4.49 5.49 | 2.9 4.4 5.4 | 2.9 4.4 5.4 | V | I _{OUT} = -50 μA |
| | | 3.0 4.5 5.5 | - - - | 2.56 3.86 4.86 | 2.46 3.76 4.76 | V | *V _{IN} = V _{IL} or V _{IH} -12 mA I _{OH} -24 mA -24 mA |
| V _{OL} | Maximum Low Level Output Voltage | 3.0 4.5 5.5 | 0.002 0.001 0.001 | 0.1 0.1 0.1 | 0.1 0.1 0.1 | V | Ι _{ΟυΤ} = 50 μΑ |
| | | 3.0 4.5 5.5 | - - | 0.36 0.36 0.36 | 0.44 0.44 0.44 | V | $*V_{IN} = V_{IL} \text{ or } V_{IH}$ 12 mA $I_{OL} \qquad 24 \text{ mA}$ 24 mA |
| I _{IN} | Maximum Input Leakage Current | 5.5 | - | ±0.1 | ±1.0 | μΑ | V _I = V _{CC} , GND |
| I _{OLD} | †Minimum Dynamic | 5.5 | - | - | 75 | mA | V _{OLD} = 1.65 V Max |
| I _{OHD} | Output Current | 5.5 | - | _ | -75 | mA | V _{OHD} = 3.85 V Min |
| I _{CC} | Maximum Quiescent Supply Current | 5.5 | - | 4.0 | 40 | μΑ | V _{IN} = V _{CC} or GND |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

*All outputs loaded; thresholds on input associated with output under test.

AC CHARACTERISTICS

| | Parameter | | 74AC | | | 74AC T _A = -40°C to +85°C C _L = 50 pF | | Unit |
|------------------------------------|---------------------|--------------------------|--------------------------------------------------|-----|-----|----------------------------------------------------------------|------|------|
| Symbol | | V _{CC} * (V) | T _A = +25°C C _L = 50 pF | | | | | |
| | | | Min | Тур | Max | Min | Max | |
| 1 | Decrease tion Delay | 3.3 | 1.5 | 5.5 | 9.5 | 1.0 | 10.0 | |
| t _{PLH} Propagation Delay | 5.0 | 1.5 | 4.0 | 8.0 | 1.0 | 8.5 | ns | |
| | Dranagation Dalov | 3.3 | 1.5 | 5.5 | 8.5 | 1.0 | 9.5 | |
| t _{PHL} Propagation De | Propagation Delay | 5.0 | 1.5 | 4.0 | 7.0 | 1.0 | 7.5 | ns |

^{*}Voltage Range 3.3 V is 3.3 V ± 0.3 V. Voltage Range 5.0 V is 5.0 V ±0.5 V.

[†]Maximum test duration 2.0 ms, one output loaded at a time. NOTE: I_{IN} and I_{CC} @ 3.0 V are guaranteed to be less than or equal to the respective limit @ 5.5 V V_{CC} .

DC CHARACTERISTICS

| | | | 74 | СТ | 74ACT | | |
|------------------|----------------------------------------|-----------------------------------------------------------------------------------------------------------------------------------|----------------|---------------------------------------|---------------|------------|----------------------------------------------------------------------------------|
| Symbol | Parameter | ameter $\begin{vmatrix} V_{CC} \\ OO \end{vmatrix} T_A = +25^{\circ}C \begin{vmatrix} -40^{\circ}C \\ -40^{\circ}C \end{vmatrix}$ | | T _A = -40°C to +85°C | Unit | Conditions | |
| | | | Тур | Guar | anteed Limits | 1 | |
| V _{IH} | Minimum High Level Input Voltage | 4.5 5.5 | 1.5 1.5 | 2.0 2.0 | 2.0 2.0 | V | V _{OUT} = 0.1 V or V _{CC} – 0.1 V |
| V _{IL} | Maximum Low Level Input Voltage | 4.5 5.5 | 1.5 1.5 | 0.8 0.8 | 0.8 0.8 | V | V _{OUT} = 0.1 V or V _{CC} – 0.1 V |
| V _{OH} | Minimum High Level Output Voltage | 4.5 5.5 | 4.49 5.49 | 4.4 5.4 | 4.4 5.4 | V | I _{OUT} = -50 μA |
| | | 4.5 5.5 | - - | 3.86 4.86 | 3.76 4.76 | V | $*V_{IN} = V_{IL} \text{ or } V_{IH}$ -24 mA I_{OH} -24 mA |
| V _{OL} | Maximum Low Level Output Voltage | 4.5 5.5 | 0.001 0.001 | 0.1 0.1 | 0.1 0.1 | V | I _{OUT} = 50 μA |
| | | 4.5 5.5 | - - | 0.36 0.36 | 0.44 0.44 | V | $V_{IN} = V_{IL} \text{ or } V_{IH}$ 24 mA I_{OL} 24 mA |
| I _{IN} | Maximum Input Leakage Current | 5.5 | - | ±0.1 | ±1.0 | μΑ | V _I = V _{CC} , GND |
| ΔI_{CCT} | Additional Max. I _{CC} /Input | 5.5 | 0.6 | _ | 1.5 | mA | V _I = V _{CC} - 2.1 V |
| I _{OLD} | †Minimum Dynamic | 5.5 | - | _ | 75 | mA | V _{OLD} = 1.65 V Max |
| I _{OHD} | Output Current | 5.5 | - | _ | -75 | mA | V _{OHD} = 3.85 V Min |
| I _{CC} | Maximum Quiescent Supply Current | 5.5 | - | 4.0 | 40 | μΑ | V _{IN} = V _{CC} or GND |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

*All outputs loaded; thresholds on input associated with output under test.

*Maximum toot direction 2.0 ms. are safetyleted with output.

AC CHARACTERISTICS

| | | | 74ACT | | | 74ACT | | | | |
|------------------|-------------------|--------------------------|-------|-----|--------------------------------------------------|-------|------|----|------|------|
| Symbol | Parameter | V _{CC} * (V) | | | T _A = +25°C C _L = 50 pF | | | | 35°C | Unit |
| | | | Min | Тур | Max | Min | Max | | | |
| t _{PLH} | Propagation Delay | 5.0 | 1.5 | _ | 9.5 | 1.0 | 10.5 | ns | | |
| t _{PHL} | Propagation Delay | 5.0 | 1.5 | - | 9.5 | 1.0 | 10.5 | ns | | |

^{*}Voltage Range 5.0 V is 5.0 V \pm 0.5 V.

CAPACITANCE

| Symbol | Parameter | Value Typ | Unit | Test Conditions |
|-----------------|-------------------------------|--------------|------|-------------------------|
| C _{IN} | Input Capacitance | 4.5 | pF | V _{CC} = 5.0 V |
| C _{PD} | Power Dissipation Capacitance | 20 | pF | V _{CC} = 5.0 V |

[†]Maximum test duration 2.0 ms, one output loaded at a time.

ORDERING INFORMATION

| Device | Marking | Package | Shipping [†] |
|---------------|---------|----------------------|-----------------------|
| MC74AC11DG | AC11 | SOIC-14 (Pb-Free) | 55 Units/Rail |
| MC74AC11DR2G | AC11 | SOIC-14 (Pb-Free) | 2500 / Tape & Reel |
| MC74ACT11DR2G | ACT11 | SOIC-14 (Pb-Free) | 2500 / Tape & Reel |

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

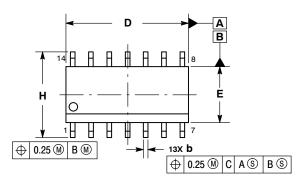


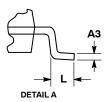


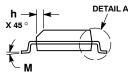
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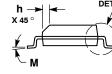
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DATE 03 FEB 2016









- NOTES:
 1. DIMENSIONING AND TOLERANCING PER
 - ASME Y14.5M, 1994.
 CONTROLLING DIMENSION: MILLIMETERS.
- DIMENSION b DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE PROTRUSION SHALL BE 0.13 TOTAL IN EXCESS OF AT
- MAXIMUM MATERIAL CONDITION.
 DIMENSIONS D AND E DO NOT INCLUDE MOLD PROTRUSIONS.
- 5. MAXIMUM MOLD PROTRUSION 0.15 PER SIDE

| | MILLIM | IETERS | INC | HES |
|-----|--------|--------|-------|-------|
| DIM | MIN | MAX | MIN | MAX |
| Α | 1.35 | 1.75 | 0.054 | 0.068 |
| A1 | 0.10 | 0.25 | 0.004 | 0.010 |
| АЗ | 0.19 | 0.25 | 0.008 | 0.010 |
| b | 0.35 | 0.49 | 0.014 | 0.019 |
| D | 8.55 | 8.75 | 0.337 | 0.344 |
| Е | 3.80 | 4.00 | 0.150 | 0.157 |
| е | 1.27 | BSC | 0.050 | BSC |
| Н | 5.80 | 6.20 | 0.228 | 0.244 |
| h | 0.25 | 0.50 | 0.010 | 0.019 |
| L | 0.40 | 1.25 | 0.016 | 0.049 |
| M | 0 ° | 7° | 0 ° | 7° |

GENERIC MARKING DIAGRAM*

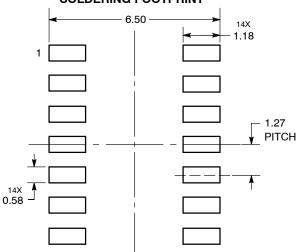


XXXXX = Specific Device Code Α = Assembly Location

WL = Wafer Lot Υ = Year WW = Work Week = Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "■", may or may not be present. Some products may not follow the Generic Marking.

SOLDERING FOOTPRINT*



DIMENSIONS: MILLIMETERS

C SEATING PLANE

STYLES ON PAGE 2

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^{*}For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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DATE 03 FEB 2016

| STYLE 1: PIN 1. COMMON CATHODE 2. ANODE/CATHODE 3. ANODE/CATHODE 4. NO CONNECTION 5. ANODE/CATHODE 6. NO CONNECTION 7. ANODE/CATHODE 8. ANODE/CATHODE 9. ANODE/CATHODE 10. NO CONNECTION 11. ANODE/CATHODE 12. ANODE/CATHODE 13. NO CONNECTION 14. COMMON ANODE | STYLE 2: CANCELLED | STYLE 3: PIN 1. NO CONNECTION 2. ANODE 3. ANODE 4. NO CONNECTION 5. ANODE 6. NO CONNECTION 7. ANODE 8. ANODE 9. ANODE 10. NO CONNECTION 11. ANODE 12. ANODE 13. NO CONNECTION 14. COMMON CATHODE | STYLE 4: PIN 1. NO CONNECTION 2. CATHODE 3. CATHODE 4. NO CONNECTION 5. CATHODE 6. NO CONNECTION 7. CATHODE 8. CATHODE 9. CATHODE 10. NO CONNECTION 11. CATHODE 12. CATHODE 13. NO CONNECTION 14. COMMON ANODE |
|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|---------------------------------------------------------------------------------------------------------------------------------------------------------------|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| STYLE 5: PIN 1. COMMON CATHODE 2. ANODE/CATHODE 3. ANODE/CATHODE 4. ANODE/CATHODE 5. ANODE/CATHODE 6. NO CONNECTION 7. COMMON ANODE 8. COMMON CATHODE 9. ANODE/CATHODE 10. ANODE/CATHODE 11. ANODE/CATHODE 12. ANODE/CATHODE 13. NO CONNECTION 14. COMMON ANODE | STYLE 6: PIN 1. CATHODE 2. CATHODE 3. CATHODE 4. CATHODE 5. CATHODE 6. CATHODE 7. CATHODE 8. ANODE 9. ANODE 10. ANODE 11. ANODE 12. ANODE 13. ANODE 14. ANODE | STYLE 7: PIN 1. ANODE/CATHODE 2. COMMON ANODE 3. COMMON CATHODE 4. ANODE/CATHODE 6. ANODE/CATHODE 6. ANODE/CATHODE 7. ANODE/CATHODE 8. ANODE/CATHODE 9. ANODE/CATHODE 10. ANODE/CATHODE 11. COMMON CATHODE 12. COMMON ANODE 13. ANODE/CATHODE 14. ANODE/CATHODE | STYLE 8: PIN 1. COMMON CATHODE 2. ANODE/CATHODE 3. ANODE/CATHODE 4. NO CONNECTION 5. ANODE/CATHODE 6. ANODE/CATHODE 7. COMMON ANODE 8. COMMON ANODE 9. ANODE/CATHODE 10. ANODE/CATHODE 11. NO CONNECTION 12. ANODE/CATHODE 13. ANODE/CATHODE 14. COMMON CATHODE |

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